

Design and status of the Mu2e crystal calorimeter

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On behalf of the MU2E Calorimeter group



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• The Mu2e experiment

- Physics case
- Experiment beamline



• Mu2e Electromagnetic Calorimeter

- Requirements and components
- Undoped CsI Crystals
- MU2E UV-extended SiPM arrays
- CsI-MPPC prototype
- Pre-production of CsI and Mu2e SiPMs
- Module 0 structure and test beam performances
- Mechanical structure
- QC of production and present status





- CLFV processes are forbidden in SM ٠
 - Even allowing neutrino oscillation BR $\sim 10^{-54}$
- **Observation of a CLFV process will be a clear evidence of New Physics**
- Mu2e : Coherent muon conversion in the electric field of a nucleus ٠
 - Broad sensitivity across different models
 - Very clear signature: monoenergetic electron



 μ -e conversion in the field of a nucleus

Improve of 4 orders of magnitude the previous limit set by the SINDRUM II experiment (6.1× 10⁻¹³) •





• Production Solenoid:

 \clubsuit Proton beam strikes target, producing mostly π

 Graded magnetic field contains backwards π/μ and reflects slow forward π/μ

• Detector Solenoid:

- ➡ Capture muons on Al target
- Measure momentum in tracker and energy in calorimeter
- ➡ Graded field "focuses" e- in tracker fiducial



• Transport Solenoid:

- Select low momentum, negative muons
- Antiproton absorber in the mid-section





General

High acceptance for reconstructing energy, time and position to provide:

- Particle Identification: e/µ separation → reject µ background
- A seed to improve track pattern recognition
- A calorimeter standalone trigger
- Operation for 1 year w.o. interruption in DS w/o reducing performance

@ 105 MeV

Calorimeter requirements

- energy resolution $\sigma_{\rm E}/{\rm E}$ <10%
- timing resolution $\sigma(t) < 500 \text{ ps}$
- position resolution < 1 cm
- Work in vacuum @ 10⁻⁴ Torr
- Work in 1 T Magnetic Field

Crystals coupled with Silicon PhotoMultipliers (SiPM)

- Light Yield (SiPM)>20 pe/MeV
- Fast signal for pileup and timing
- Survive a high radiation environment
 - Total Ionizing Dose (TID) of 90 krad/5 years for crystals
 - TID of 75 krad/5 years for sensors
 - $3x10^{12}$ n/cm² for crystals
 - $1.2x10^{12}$ n/cm² for sensors





The calorimeter consists of two disks to optimize acceptance for spiraling electrons with 674 34x34x200 mm³ undoped CsI crystals:

- \rightarrow R_{inner} = 375 mm, R_{outer}=657 mm
- \rightarrow depth = 10 X₀ (200 mm) but CE angle of 55°
- \rightarrow Disks separated by 75 cm
- → Each crystal is readout by two large area UV extended SIPM's (12x18 mm²) for redundancy
- → Analog FEE is on the SiPM and digital electronics located in near-by electronics crates
- → Radioactive source and laser system provide absolute calibration and monitoring capability
- → Crystals and sensors should work in 1 T B-field and in vacuum of 10⁻⁴ Torr







- High light output (LO) > 100 p.e./MeV by standard bialkali PMT with air gap and crystal wrapped with 150 μm Tyvek paper
- Good light response uniformity (LRU) < 10 %
- Fast signal with small slow component: τ < 40ns and F/T = F(Integral in 200 ns)/T(Integral in 3000 ns) >75%

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	LYSO	BaFz	Csl
Radiation Length X ₀ [cm]	1.14	2.03	1.86
Light Yield [% NaI(Tl)]	75	4 / <u>36</u>	3.6
Decay Time[ns]	40	0.9 /650	20
Photosensor	APD	RMD APD	SiPM
Wavelength [nm]	402	220 /300	310



S-G C0063	SIC C0071		
S-G C0065	SIC C0072		
S-G C0066	SIC C0073		

Csl(pure)

- Adequate radiation hardness
- Slightly hygroscopic
- 30 ns emission time, small slow component.
- Emits @ 310 nm.
- Comparable LY of fast component of BaF₂.
- Lower cost (6-8 \$/cc)

CsI+MPPC test



- A small crystal prototype has been built • and tested in Frascati in April 2015
- 3x3 matrix of 3x3x20 cm³ un-doped CsI ۲ crystals coupled with UV-extended MPPC (standard 4x4 matrix of 3x3mm² TSV).
- Test with e- between 80 and 120 MeV •

90

Energy Resolution [%]

8.5

8

7

6.5₽ 6

5.5

4.5

Data

MC

80

70







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- Crystal dimension increased to 34x34 mm² to house two 2x3 arrays of 6x6mm² UV-extended SiPM
- 24 crystals from three different vendors: SICCAS, Amcrys, Saint Gobain
- ²²Na source to test crystal properties along the crystal axis
- Crystals coupled in air to an UV-extended PMT



SiPM pre-production

Mu2e custom silicon photosensors:

 \rightarrow 2 arrays of 3 6x6 mm² UV-extended SiPMs: total area (12x18) mm²

150 sensors: 3×50 Mu2e pre-production SiPMs from Hamamatsu, SenSI and AdvanSiD

The readout series configuration reduces the overall

capacitance \rightarrow faster signals







See I.Sarra poster









SiPM irradiated at ENEA Casaccia with 20krad ⁶⁰Co photon source producing negligible effect on the response and on leakage current

- Neutron irradiation tested at ENEA Frascati (FNG) with 14 MeV neutrons.
- □ Total flux 2.2x10¹¹ n/cm² (2.2 times the experiment lifetime)
- □ Leakage current increases to too high values asking for cooling at lower temperatures the sensors.

By measuring the dependence of the leakage current as a function of temperature, we observe a factor of 10 reduction in ldark when working at T = 0 °C that is acceptable.

So, we require to cool down all SIPMs to a running temperature of \sim 0 °C.





Module 0



Large size prototype: 51 crystals coupled to 102 sensors



- Goals:
 - Test the performances
 - Test integration and assembly procedures
 - e⁻ beam (60-120 MeV), May 2017
 - Orthogonal and 50° incidence (CE)
 - Operate under vacuum, low temperature and irradiation tests
- Readout: 1 GHz CAEN digitizers (DRS4 chip), 2 boards x 32 channels









Module 0 Test Beam





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120

120

Orthogonal incidence

Single particle selection . **≥**09 **Me** 1902 Entries Mean 87.87 Calibration: • **Entries/1** 50 7.702 Std Dev χ^2 / ndf 23.5/12 Cosmic 0.2011 ± 0.0846 4.723 ± 0.199 Beam 100 89.48 ± 0.29 μ 1552 ± 50.2 80 Orthogonal Run: 60 - DATA σ_F~ 5% MC 40 Tilted Run: 20 σ_E~ 7.5% 0 20 80 100 40 60 $@ E_{beam} = 100 MeV$ E [MeV] 50° incidence 90 Entries/ 1 MeV DATA: Orthogonal Bean o/E_{dep} [%] 1190 Entries DATA: Beam @ 50 80 MC: Orthogonal Beam γ^2 / ndf 26.39 / 27 70 MC: Beam @ 50 0.07021 ± 0.04812 60 6.572 ± 0.202 7 88.12 ± 0.38 50 6 1108 ± 33.8 40 $\frac{a}{\sqrt{E}} \oplus \frac{b}{E} \oplus c$ $\frac{\sigma_E}{E}$ 5Ē 30 DATA χ^2 / ndf 3.142/3 χ^2 / ndf 0.8783 / 2 MC 20 3 0.6 ± 0 0.6 ± 0 а 10 b 0.2732 ± 0.02913 0.3747 ± 0.045 5.863 ± 0.3911 0<mark>.</mark> 4.05 ± 0.2705 С С 20 100 40 60 80 E [MeV] 0^b

0.11 E_{dep} [GeV]

0.1

0.08

0.09

0.05

0.06

0.07



Module 0 – Time resolution



- Log Normal fit on leading edge
- Constant Fraction method used CF = 5%
- Comparison between 1GHz (TB sampling) and 200 MHz (Mu2e sampling) shows no deterioration in the resolution
- Test with CR at low temperature in vacuum (scint trigger)





 σ (T1+T2)/ $\sqrt{2}$ ~ 132 ps @ E_{beam} = 100 MeV



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- Square crystals stacked from the bottom for increasing rows inside an external stainless steel cylinder
- Inner cylinder in composite material
- FEA completed, good stability of the system, small stress on legs
- Readout back plate in PEEK used for FEE positioning and cooling SiPMs at low temperature.
- Front face integrated with routing of Source Tubing
- FEE crates connected to the external cylinder



Detector 1:1 mockup with fake iron crystals



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Dedicated board on each SiPM for:

- Amplification stage (x15, x30)
- Linear regulation of bias
- Rise time 15 ns
- Dynamic range 2V
- Monitoring of the current
- Pulse signal for testing
- Therma-Bridge to dissipate heat

10 crate per disk with 8 differential channels boards:

- HV distributor (1st board)

690 ma

- WD boards (2nd board) with:
 - FPGA PF300T
 - 200 Msps-12 bit ADC
 - DCDC converter
 - Optical connection

See E.Pedreschi poster



Calorimeter calibration





- Pre-insertion calibration with 6 MeV source
- Weekly crystal-by-crystal calibration ٠ with 6 MeV source
- Monitor readout on shorter time ٠ scale with Laser system
- Monitor electronics gains with pulser
- **Monitor temperatures**

6 MeV gamma source:

Low energy neutron from DT generator irradiate Fluorinert fluid outside detector

 ${}^{19}F + n \rightarrow {}^{16}N + \alpha$ ${}^{16}N \rightarrow {}^{16}O^* + \beta \quad t_{1/2} = 7 \text{ s}$ ${}^{16}O^* \rightarrow {}^{16}O + \gamma(6.13 \text{ MeV})$

DT generator: $d+t \rightarrow n(14.2 \text{ MeV})$: 10^9 n/s







- Crystal and SiPM production started on February 2018. QC started on March 2018.
 - ~2000 SiPMs tested
 - ~500 crystals

Csl dimensional test





Csl RIN



SIPM dimensional test



SiPM QA



SiPM MTTF





Crystals QC





- specifications concerning optical properties
- Some problems to satisfy the mechanical specs for SG but now solved in new production
- □ End in May 2019





SiPM QC





- Large Scale characterization shows stable results on ~2000 Mu2e SiPMs tested.
- Only 0.6% of SiPMs rejected
- End in June 2019







- The Mu2e calorimeter has concluded its prototyping phase satisfying the Mu2e requirements:
 - Un-doped CsI crystals perform well
 - Excellent LRU and LY 100 pe/MeV (PMT+Tyvek wrapping)
 - τ of 30 ns with negligible slow component
 - Radiation hardness OK for our purposes: 40% LY loss at 100 krad
 - Mu2e SiPMs quality OK, high gain, high PDE, small I_{dark}, small spread inside array
 - SiPM performance after irradiation OK
 - SiPM MTTF > 3 million hours
 - Calorimeter prototypes tested with e⁻ beam
 - Good time and energy resolution achieved @ 100 MeV
- Calorimeter production phase started

Mid 2019: start of calorimeter construction End 2020: installation into experimental hall

Additional material



MU2E sensitivity





Beam structure





❑ Use the fact that muonic atomic lifetime >> prompt background Need a pulsed beam to wait for prompt background to reach acceptable levels → Fermilab provides the beam we need !

OUT of time protons are also a problem->prompt bkg arriving late... To keep associated background low we need proton extinction of 10⁻¹⁰: proton extinction (between pulses) → # protons out of beam/# protons in pulse









- Intrinsic scale with no. stopped muons
 - $-\mu$ Decay-in-Orbit (DIO)
 - Radiative muon capture (RMC)
- Late arriving scale with no. late protons
 - Radiative pion capture (RPC)
 - $-~\mu$ and π decay-in-flight (DIF)
- Miscellaneous
 - Anti-proton induced
 - Cosmic-ray induced

Category	Source	Events
	μ Decay in Orbit	0.20
Intrinsic	Radiative µ Capture	<0.01
	Radiative π Capture	0.02
	Beam electrons	<0.01
	μ Decay in Flight	<0.01
Late Arriving	π Decay in Flight	<0.01
	Anti-proton induced	0.05
Miscellaneous	Cosmic Ray induced	0.10
Total Background		0.37

(assuming 6.8E17 stopped muons in 6E7 s of beam time)



The most sneaky source of background comes from Stopped Muons

$$[\mu^{-} + A(N,Z)]^{1S}_{bound} \rightarrow A(N,Z) + e^{-} + \overline{\nu}_{e} + \nu_{\mu}$$

- For decay-in-orbit muons, the maximum energy of the electron is equal to the energy of a conversion electron
- The high energy tail falls as (Ece-Ee)⁵
- 10-17 of the spectrum is within 1 MeV from the endpoint
- An excellent momentum resolution is needed to beat this background







• Proton absorber:

made of high-density polyethylene
designed in order to reduce proton flux on the tracker and minimize energy loss

Targets:

♦ 17 Al foils; Aluminum was selected mainly for the muon lifetime in capture events (864 ns) that matches nicely the need of prompt separation in the Mu2e beam structure.



• Tracker:

- 21600 tubes arranged in planes on stations, the tracker has 18 stations
- Expected momentum resolution ~ 120 keV/c

Calorimeter:

2 disks composed of CsI crystals and separated by 1/2 wavelength

Muon beam stop:

made of several cylinders of different materials: stainless steel, lead and high density polyethylene









 A signal electron, together with all the other "stuff" occurring simultaneously, integrated over 500-1695 ns window





Simulation





- Simulation includes full background and digitization and cluster-finding, with split-off and pileup recovery
- The overall resolution depends on crystals features
 - Several crystals considered

	LYSO	BaFz	Csl
Radiation Length X ₀ [cm]	1.14	2.03	1.86
Light Yield [% Nal(Tl)]	75	4 /36	3.6
Decay Time[ns]	40	0.9 /650	20
Photosensor	APD	RMD APD	SiPM
Wavelength [nm]	402	220 /300	310



~ 55 ps/sqrt(E/GeV)







Noise term *b* considered negligible (~0.1% in quadrature).

32



Test on different vendors performed:

- ISMA (Ukraine) •
- SICCAS (China)
- **OptoMaterial** (Italy)
- CsI crystals irradiated up to 900 Gy and • to a neutron fluency up to 9×10^{11} n_{1MeV}/cm^2 @Caltech (USA) and CALLIOPE and FNG in ENEA(Italy)
- The ionization dose does not modify • LRU while a 20% reduction in LY is observed at 900 Gy.
- Similarly, the neutron flux causes an • acceptable LY deterioration (< 15%).







- Longitudinal transmittance (LT) was measured by using a Perkin-Elmer Lambda 950 spectrophotometer. (0.15%)
- Pulse height spectrum (PHS), FWHM energy resolution of 511KeV gamma-rays (ER), light output (LO), light response uniformity(LRU) and decay kinetics were measured by a Hamamatsu R2059 PMT with coincidence triggers from a 22Na source. All samples were wrapped with two layers of Tyvek paper with precision and reproducibility of <1%.
- PHS/ER/LO/LRU were measured with air gap for pure CsI because of the soft and hygroscopic surface.







LO is defined as the average of LO values measured at seven points with rms spread as LRU

Decay kinetics was measured at the point closest to the PMT with F/T ratio specified





Assuming 230 days' run (2×10^7 sec) each year, the hottest crystals would have the following radiation environment:

- Neutron fluence: 2×10^{11} n/cm²/year $\rightarrow 1.0 \times 10^{4}$ n/cm²/s.

The energy equivalent noise (σ) is derived as the standard deviation of photoelectron number (Q) in the readout gate:

$$\sigma = \frac{\sqrt{Q}}{LO} \qquad \text{(MeV)}$$





We have tested arrays of 16 3x3 mm² Hamamatsu TSV MPPCs (12x12 mm²)

- These have silicon and thin film protection layers
- SiPMs are coupled to pure CsI crystals (30x30x200) mm³
- \rightarrow ~ 30 (20) p.e./MeV with (without) optical grease with Tyvek-wrapped crystals
- → Time resolution < 150 ps @ 100 MeV with 45° e^{-} impact angle
- \rightarrow Energy resolution better than 7% at 100 MeV (leakage dominated)
- \rightarrow Equivalent noise ~ 100 keV



Thin Film coating and Silicon resin coating has PDE advantage in UV region.





i1





- Decay time can be regulated at the shaping level, but a high detector capacitance increases noise (worsens the signal-to-noise ratio)
- When SiPMs are connected in series, the voltage applied to each SiPM is determined by the common leakage current. Then, the difference in breakdown voltages is absorbed, and the over-voltages are approximately aligned. It depends on "how much the I-V curve are similar"





Starting point: after 6 years of Running

We have measured, for a 3x3 mm² MPPC, a leakage current of 2.3 mA after a flux of 2.2x10¹¹ n_14MeV/cm² (4x10¹¹ n_1MeV/cm²) @ 25°C

 \rightarrow This corresponds to 9 mA for a 6x6 mm² MPPC @ 25°C

- 1) Assuming a factor 2 for annealing
- \rightarrow 4.5 mA per a MPPC of 6x6 mm² @ 25°C (Vop)

for the proposed SiPM (matrix 2x3 of 6x6 mm²) we expect:

 \rightarrow 9 mA for the parallel of two series @ 25°C

2) We have measured a leakage current reduction of a factor 5 operating at 0°C

 \rightarrow 9/5 = 1.8 mA for the device @ 0°C

3) we can take advantage of an additional factor of 2 if needed by lowering of 0.5 V the Vbias with respect to Vop (@ 0° C)

 \rightarrow 1.8/2 = 1 mA @ 0°C

at the experiment end, we will get 1 mA with 200 V of bias, 200 mW @ 0°C , Vop-0.5 V for the innermost Layer of Disk 1 \rightarrow 120 crystals \rightarrow 240 photosensors